

CR5AS-12A

600V - 5A - Thyristor
Medium Power Use

R07DS0332EJ0300

Rev.3.00

Jan 23, 2013

Features

- $I_{T(AV)}$: 5 A
- V_{DRM} : 600 V
- I_{GT} : 100 μ A
- Non-Insulated Type
- Plannar Type

Outline

RENESAS Package code: PRSS0004ZG-A
(Package name: MP-3A)



PRSS0004ZD-D
(Package name: DPAK(L)-(3))



Applications

Switching mode power supply, regulator for autcycle, protective circuit for TV sets, VCRs, and printers, igniter for autcycle, electric tool, strobe flasher, and other general purpose control applications

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		12	
Repetitive peak reverse voltage	V_{RRM}	600	V
Non-repetitive peak reverse voltage	V_{RSM}	720	V
DC reverse voltage	$V_R (DC)$	480	V
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	600	V
DC off-state voltage ^{Note1}	$V_D (DC)$	480	V

Notes: 1. With gate to cathode resistance $R_{GK} = 220 \Omega$.

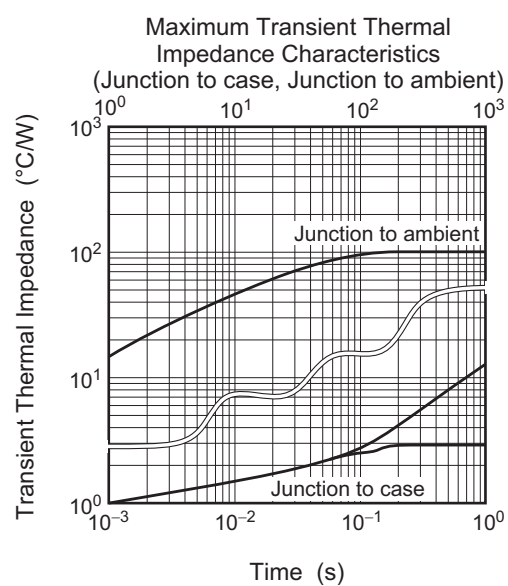
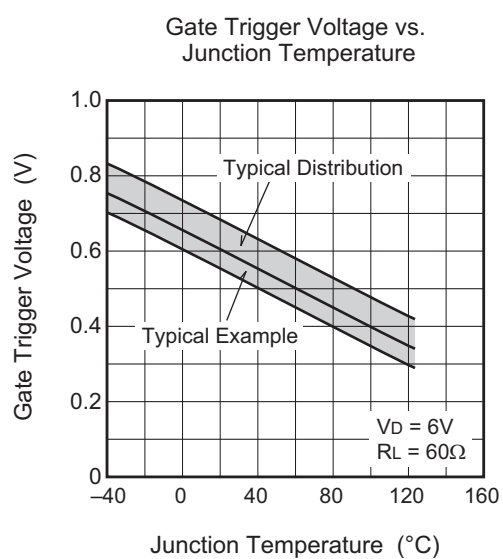
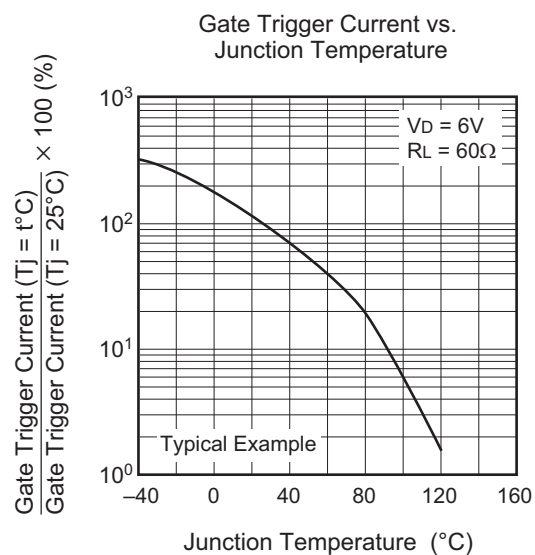
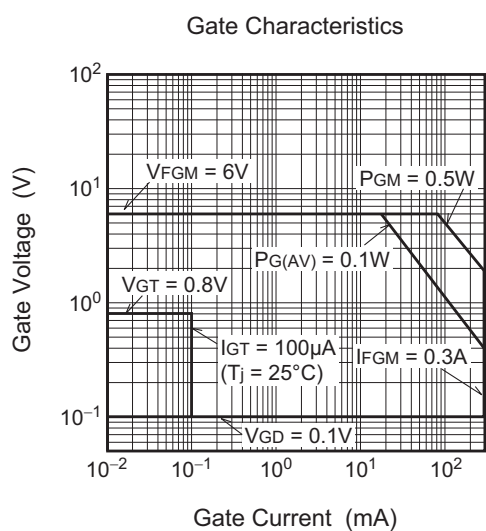
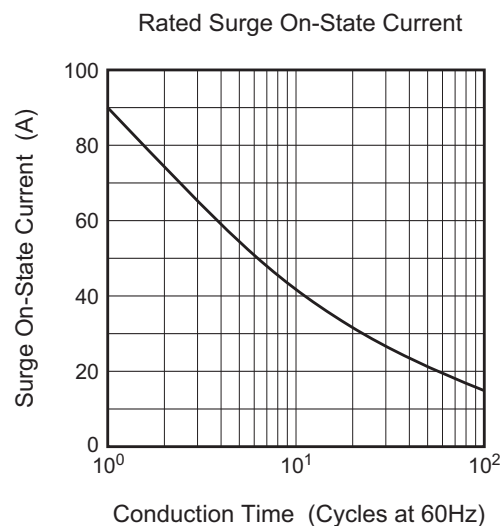
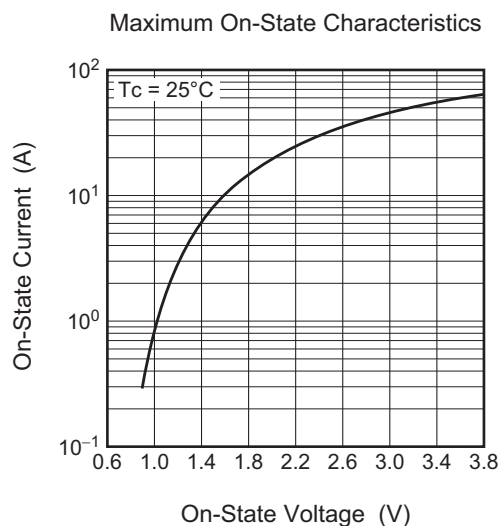
Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_{T(RMS)}$	7.8	A	
Average on-state current	$I_{T(AV)}$	5	A	Commercial frequency, sine half wave 180° conduction, $T_c = 88^\circ\text{C}$
Surge on-state current	I_{TSM}	90	A	60Hz sine half wave 1 full cycle, peak value, non-repetitive
I^2t for fusing	I^2t	33	A^2s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P_{GM}	0.5	W	
Average gate power dissipation	$P_{G(AV)}$	0.1	W	
Peak gate forward voltage	V_{FGM}	6	V	
Peak gate reverse voltage	V_{RGM}	6	V	
Peak gate forward current	I_{FGM}	0.3	A	
Junction temperature	T_j	- 40 to +125	$^\circ\text{C}$	
Storage temperature	T_{stg}	- 40 to +125	$^\circ\text{C}$	
Mass	—	0.32	g	MP-3A, Typical value
	—	0.36	g	DPAK(L)-(3), Typical value

Electrical Characteristics

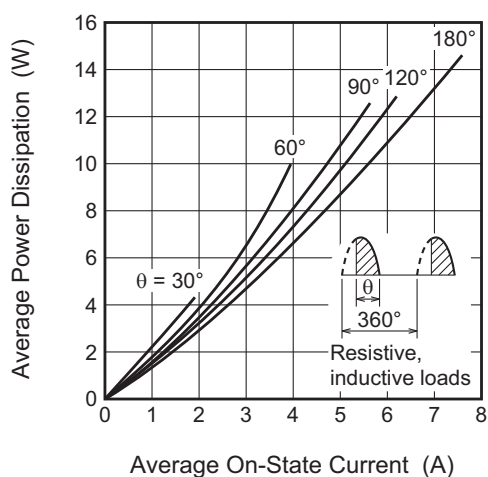
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Repetitive peak reverse current	I_{RRM}	—	—	1.0	mA	$T_j = 125^\circ\text{C}$, V_{RRM} applied, $R_{GK} = 220\ \Omega$
Repetitive peak off-state current	I_{DRM}	—	—	1.0	mA	$T_j = 125^\circ\text{C}$, V_{DRM} applied, $R_{GK} = 220\ \Omega$
On-state voltage	V_{TM}	—	—	1.8	V	$T_c = 25^\circ\text{C}$, $I_{TM} = 15\ \text{A}$, instantaneous value
Gate trigger voltage	V_{GT}	—	—	0.8	V	$T_j = 25^\circ\text{C}$, $V_D = 6\ \text{V}$, $I_T = 0.1\ \text{A}$
Gate non-trigger voltage	V_{GD}	0.1	—	—	V	$T_j = 125^\circ\text{C}$, $V_D = 1/2\ V_{DRM}$, $R_{GK} = 220\ \Omega$
Gate trigger current	I_{GT}	1	—	100	μA	$T_j = 25^\circ\text{C}$, $V_D = 6\ \text{V}$, $I_T = 0.1\ \text{A}$
Holding current	I_H	—	3.5	—	mA	$T_j = 25^\circ\text{C}$, $V_D = 12\ \text{V}$, $R_{GK} = 220\ \Omega$
Thermal resistance	$R_{th(j-c)}$	—	—	3.0	$^\circ\text{C/W}$	Junction to case ^{Note2}

Notes: 2. The measurement point for case temperature is at anode tab.

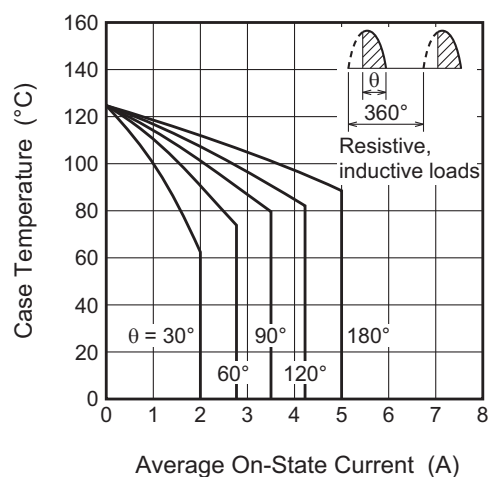
Performance Curves



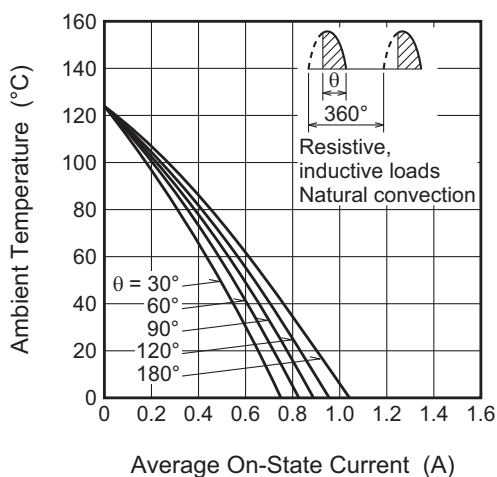
Maximum Average Power Dissipation
(Single-Phase Half Wave)



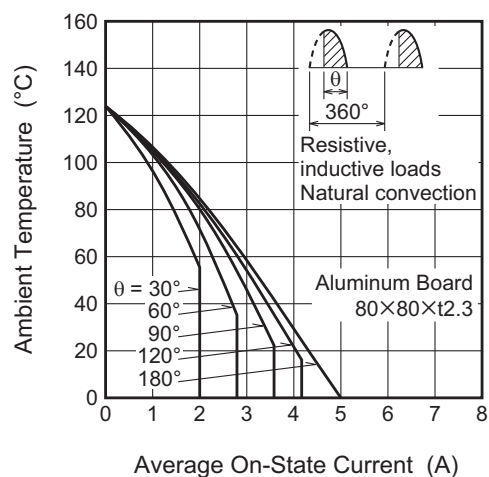
Allowable Case Temperature vs.
Average On-State Current
(Single-Phase Half Wave)



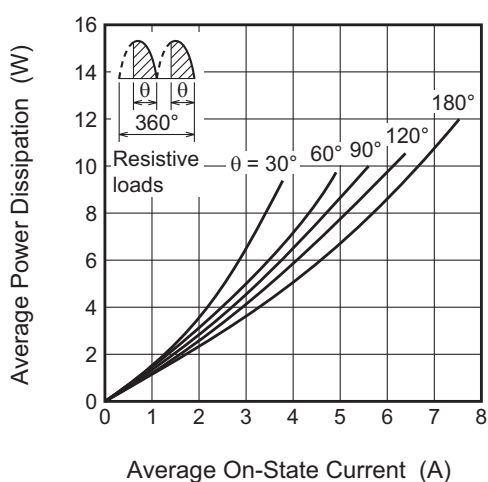
Allowable Ambient Temperature vs.
Average On-State Current
(Single-Phase Half Wave)



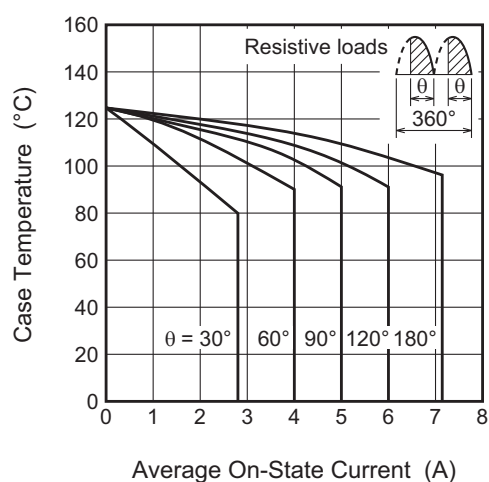
Allowable Ambient Temperature vs.
Average On-State Current
(Single-Phase Half Wave)



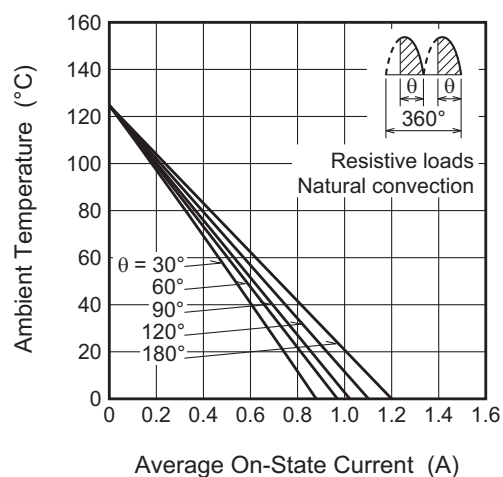
Maximum Average Power Dissipation
(Single-Phase Full Wave)



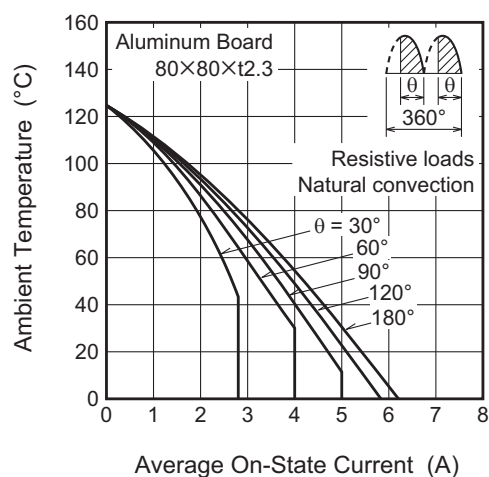
Allowable Case Temperature vs.
Average On-State Current
(Single-Phase Full Wave)



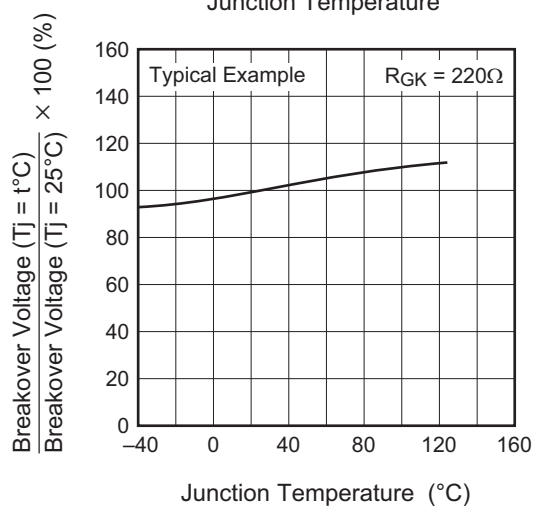
Allowable Ambient Temperature vs.
Average On-State Current
(Single-Phase Full Wave)



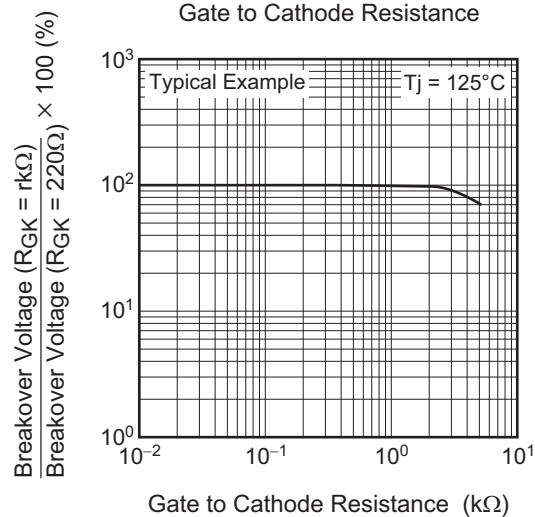
Allowable Ambient Temperature vs.
Average On-State Current
(Single-Phase Full Wave)



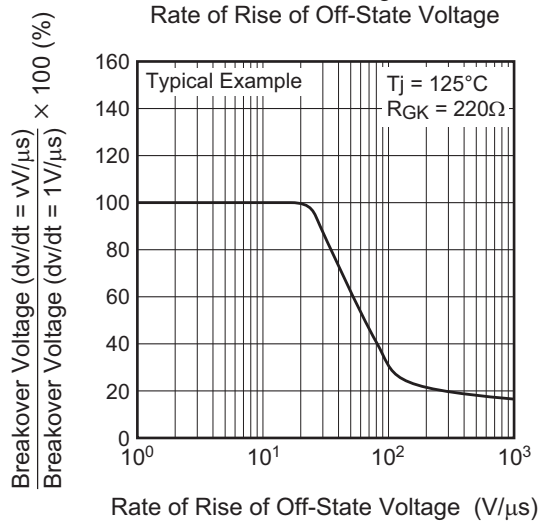
Breakover Voltage vs.
Junction Temperature



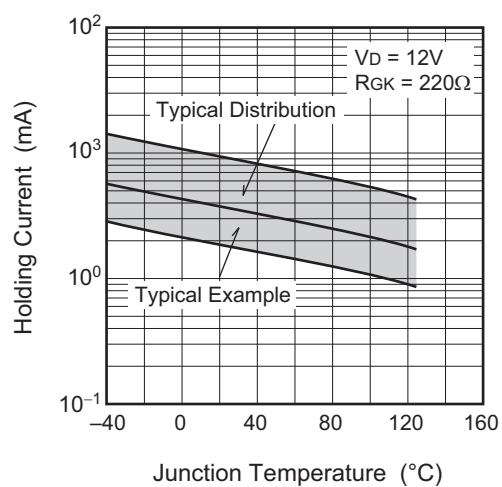
Breakover Voltage vs.
Gate to Cathode Resistance



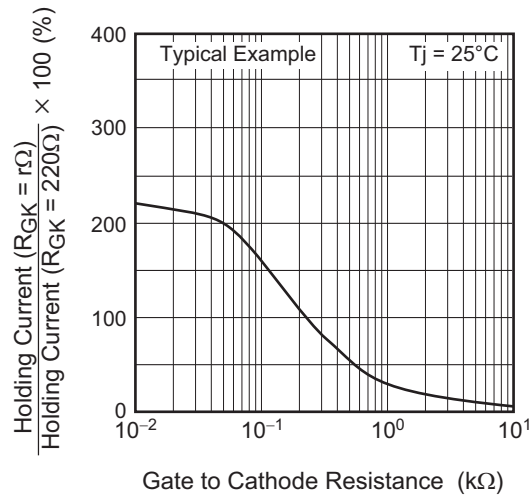
Breakover Voltage vs.
Rate of Rise of Off-State Voltage



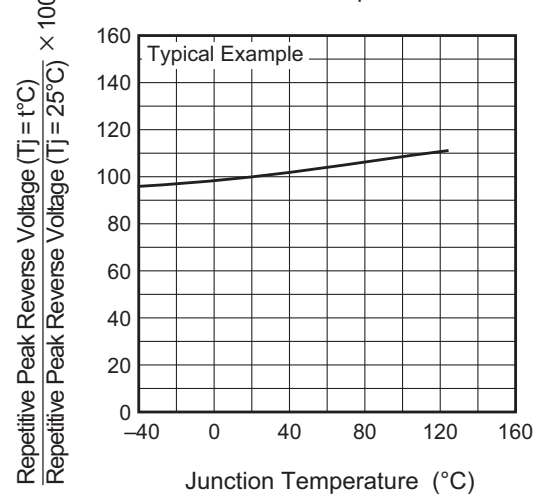
Holding Current vs.
Junction Temperature



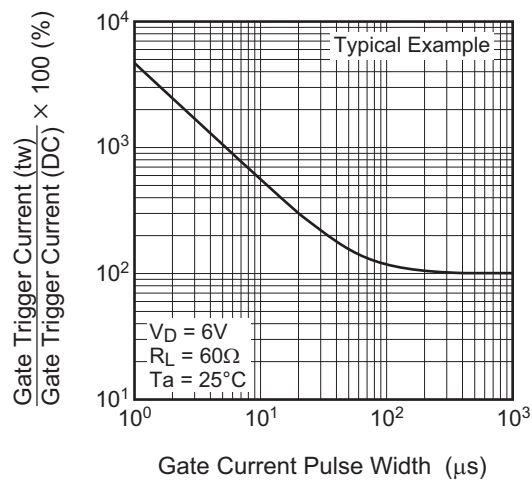
Holding Current vs.
Gate to Cathode Resistance



Repetitive Peak Reverse Voltage vs.
Junction Temperature



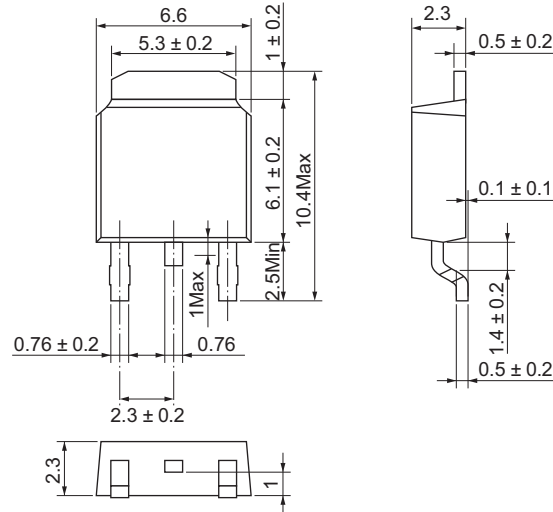
Gate Trigger Current vs.
Gate Current Pulse Width



Package Dimensions

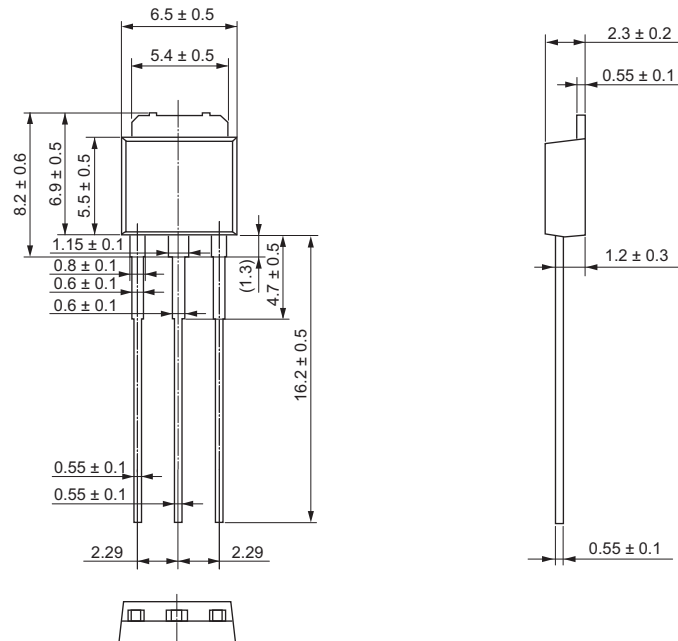
Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
MP-3A	SC-63	PRSS0004ZG-A	TMP3	0.32g

Unit: mm



Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
DPAK(L)-(3)	—	PRSS0004ZD-D	DPAK(L)-(3)/DPAK(L)-(3)V	0.36g

Unit: mm



Ordering Information

Orderable Part Number	Packing	Quantity	Package	IGT
CR5AS-12A#B01	Tube	75 pcs.	MP-3A	1-100 μ A
CR5AS-12A#C04	Tube	75 pcs.	MP-3A	20-50 μ A
CR5AS-12A#C05	Tube	75 pcs.	MP-3A	20-100 μ A
CR5AS-12A-T13#B01	Embossed Tape	3000 pcs.	MP-3A	1-100 μ A
CR5AS-12A-T13#C04	Embossed Tape	3000 pcs.	MP-3A	20-50 μ A
CR5AS-12A-T13#C05	Embossed Tape	3000 pcs.	MP-3A	20-100 μ A
CR5AS-12A-A1#B00	Tube	80 pcs.	DPAK(L)-(3)	1-100 μ A
CR5AS-12A-BA1#B00	Tube	80 pcs.	DPAK(L)-(3)	20-50 μ A
CR5AS-12A-EA1#B00	Tube	80 pcs.	DPAK(L)-(3)	20-100 μ A

Note : Please confirm the specification about the shipping in detail.

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